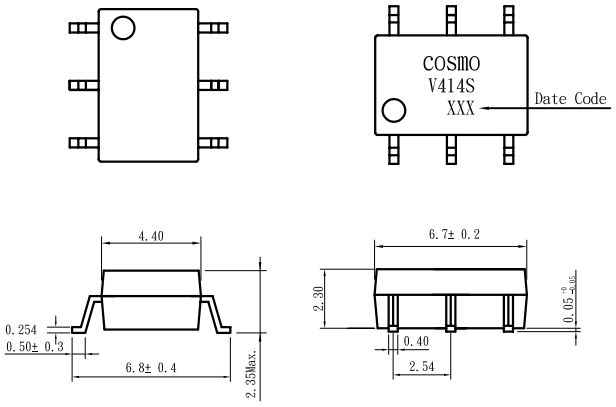
PRODUCT SPECIFICATION

DATE:08/28/2002

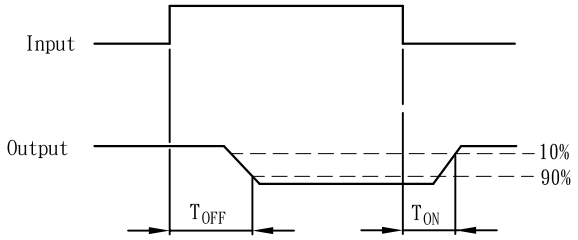
COSMO ELECTRONICS CORPORATION	PHOTO $^{E}_{D}$MOS RELAYS: KAQV414S	NO.62M11002	REV.
		SHEET 1 OF 7	1

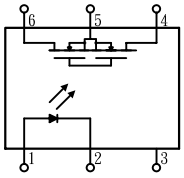
• OUTSIDE DIMENSION :

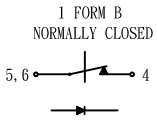


Unit:mm
Tolerance:± 0.2 mm

• Operate/Reverse time







Absolute Maximum Ratings (T_A=25° C)

Emitter (Inpute)

Reverse Voltage 5.0V
Continuous Forward Current 50mA
Peak Forward Current (1s) 1A
Power Dissipation. 100mW
Derate Linearly from 25° C . . . . . 1.3mW/° C

Detector (Output)

Output Breakdown Voltage . . . . . .± 400V
Continous Load Current . . . . . ± 130mA
Power Dissipation 500mW

General Characteristics

Isolation Test Voltage. . . . . .1500VAC$_{RMS}$
Isolation Resistance
V_{IO} =500V, T_A=25° C. . . . . $\geq 10^{10}\Omega$
Total Power Dissipation 550mW
Derate Linearly form 25° C. . . . . .2.5mW/° C
Storage Temperature Range . . . . -40 to +150° C
Operating Temperature Range. . . . -40 to +85° C
Junction Temperature . . . . . .100° C
Soldering Temperature, 2mm from case, 10 sec. 260° C

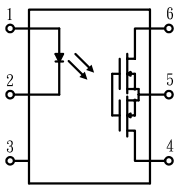
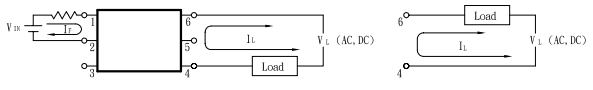
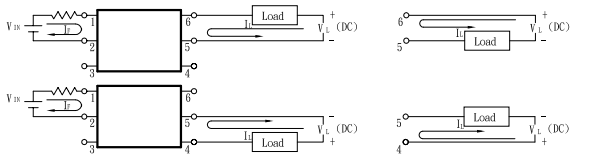
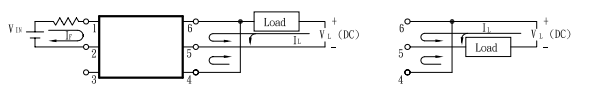
PRODUCT SPECIFICATION

DATE:08/28/2002

COSMO ELECTRONICS CORPORATION	PHOTO EMOS RELAYS: KAQV414S	NO. 62M11002	REV.
		SHEET 2 OF 7	1

Characteristics (T_A=25° C)

Description			Symbol	Min.	Typ.	Max.	Unit	Test Condition
Emitter (Input)								
Forward Voltage			V_F		1.2	1.5	V	I_F =10mA
Operation Input Current			I_{FOFF}			5	mA	V_L=± 20V, I_L=<5uA,
Recovery Input Current			I_{FON}	0.2			mA	V_L=± 20V, I_L=100mA t=10 ms
Deterctor (Output)								
Output Breakdown Voltage			V_B	400			V	I_B=50uA
Output Off-State Leakage			$I_{T(OFF)}$		0.2	1	uA	V_T=100V, I_F=10mA
I/O Capacitance			C_{ISO}		6		pF	I_F=0, f=1MHz
ON Resistance	Connection	A	R_{ON}		25	50	Ω	I_L=100mA, I_F=0mA
		B			14	25		
		C			7	12.5		
Reverse(ON) Time			T_{ON}		0.6	1.5	ms	I_F=10mA, V_L=± 20V
Operate(OFF) Time			T_{OFF}		0.3	1.0	ms	t=10ms, I_L=± 100mA

Mos Relay Schematic and Wiring Diagrams					
Type	Schematic	Output configur-ation	Load	Con-nection	Wiring diagram
KAQV414S		1b	AC/DC	A	
			DC	B	
			DC	C	

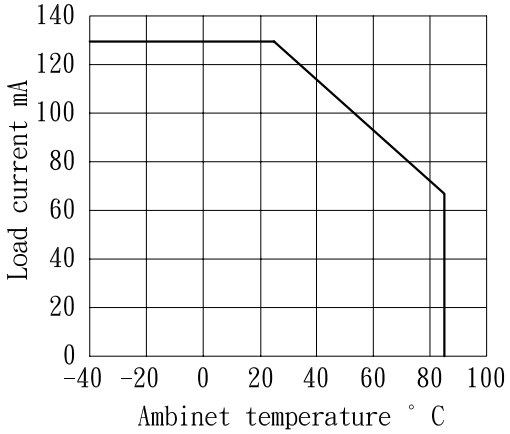
PRODUCT SPECIFICATION

DATE:08/28/2002

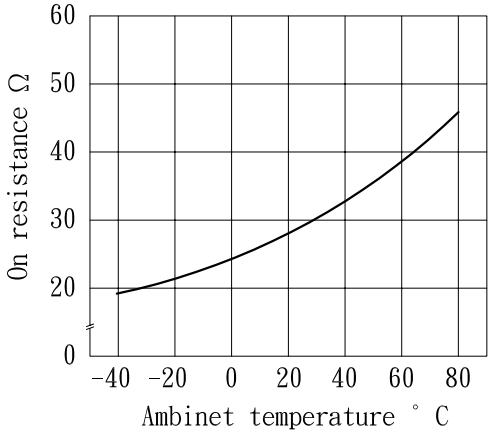
COSMO ELECTRONICS CORPORATION	PHOTO MOS RELAYS: KAQV414S	NO.62M11002	REV.
		SHEET 3 OF 7	1

DATA CURVE

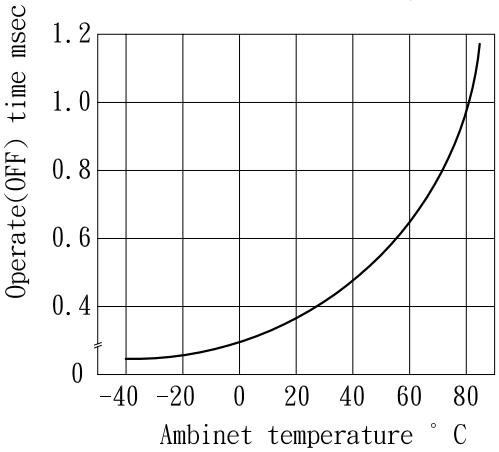
Load current vs. ambient temperature
Allowable ambient temperature:
-40° C+85° C



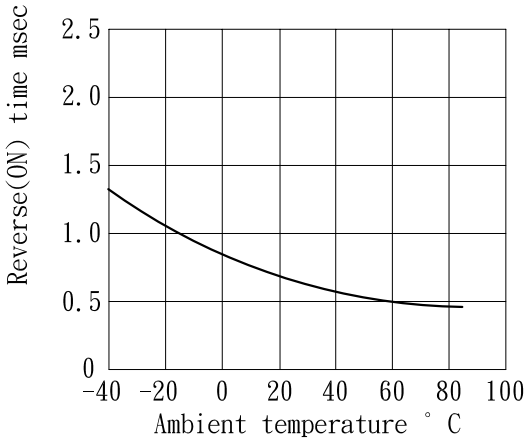
On resistance vs. ambient temperature
Across terminals 4 and 6 pin
LED current: 5mA
Continuous load current: 130 mA(DC)



Operate(OFF) time vs. ambient temperature
Load voltage 400 V(DC)
LED current :5mA
Continuous load current: 130mA(DC)



Reverse(ON) time vs. ambient temperature
LED current: 5mA;Load voltage: 400V(DC)
Continuous load current: 130mA(DC)

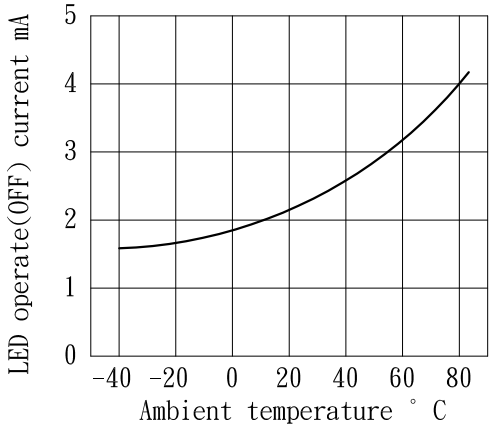


PRODUCT SPECIFICATION

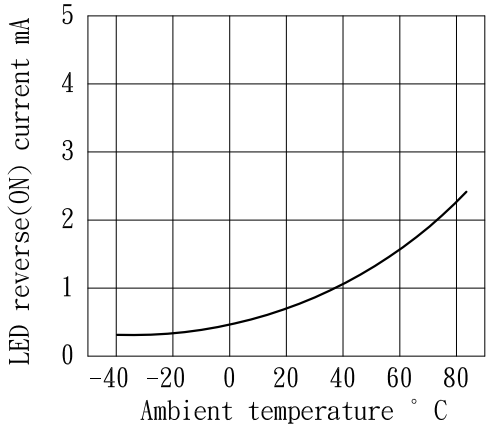
DATE:08/28/2002

COSMO ELECTRONICS CORPORATION	PHOTO MOS RELAYS: KAQV414S	NO.62M11002	REV.
		SHEET 4 OF 7	1

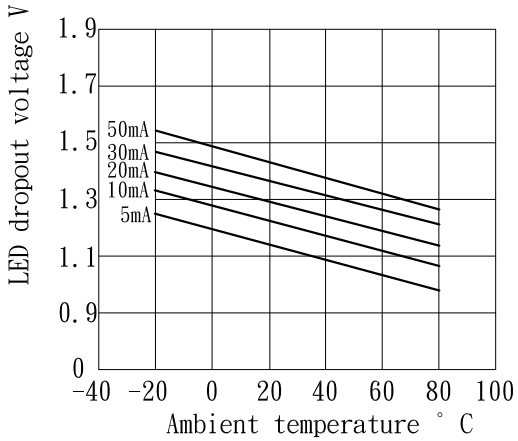
LED operate(OFF) vs. ambient temperature
Load voltage: 400V(DC)
Continuous load current: 130mA(DC)



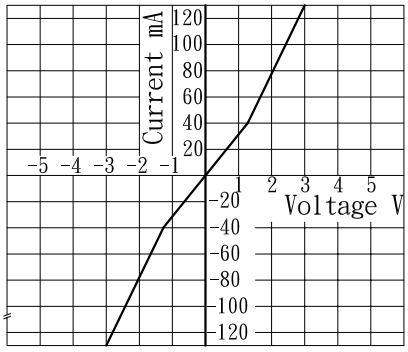
LED reverse(ON) current vs. ambient temperature
Load voltage: 400V(DC)
Continuons load current: 130mA(DC)



LED dropout voltage vs. ambient temperature
LED current: 5 to 50mA



Voltage vs. current characteristics of output at MOS FET portion
Measured portion: across terminals 4 and 6 pin
Ambient temperature: 25° C

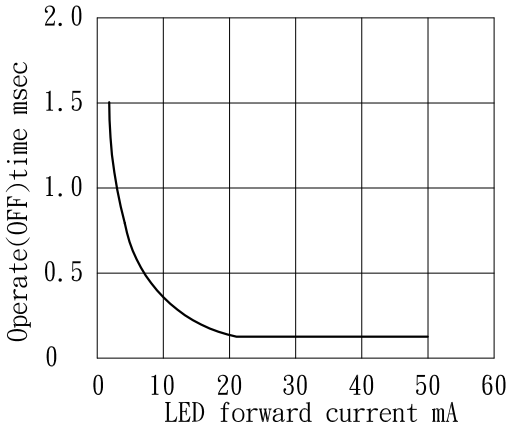


PRODUCT SPECIFICATION

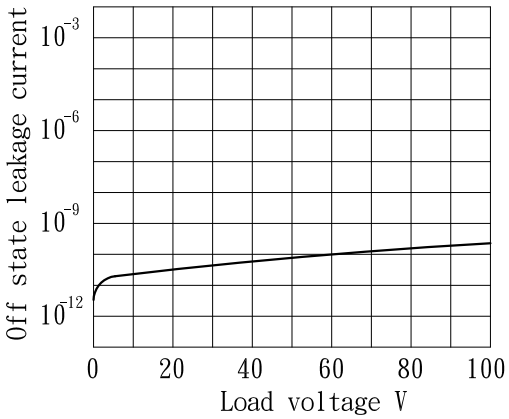
DATE:08/28/2002

COSMO ELECTRONICS CORPORATION	PHOTO MOS RELAYS: KAQV414S	NO.62M11002	REV.
		SHEET 5 OF 7	1

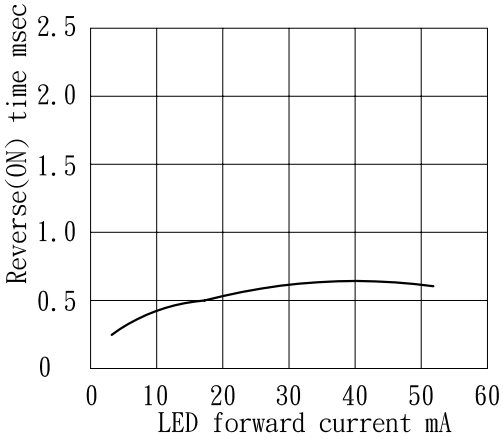
LED forward current vs. Operate(OFF) time
Across terminals 4 and 6pin;Load voltage: 400V(DC);Continuous load current:130mA(DC) ;Ambient temperature: 25。C



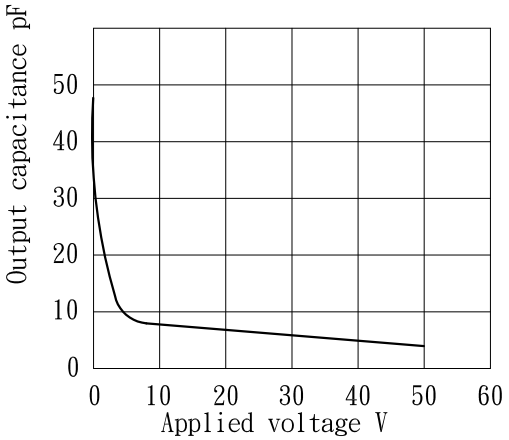
Off state leakage current
Across terminals 4 and 6pin
Ambient temperature: 25° C



LED forward current vs. reverse(ON) time
Across terminals 4 and 6pin;Load voltage: 400V(DC);Continuous load current: 130 mA(DC);Ambient temperature: 25° C



Applied voltage vs. output capacitance
Across terminals 4 and 6pin
Frequency: 1MHz;Ambient temperature: 25° C



PRODUCT SPECIFICATION

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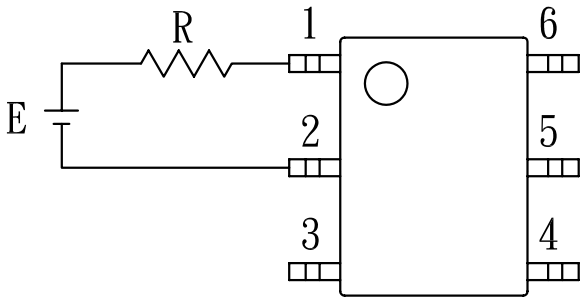
COSMO ELECTRONICS CORPORATION	PHOTO MOS RELAYS: KAQV414S	NO.62M11002	REV.
		SHEET 6 OF 7	1

USING METHODS

Examples of resistance value to control LED forward current I_F

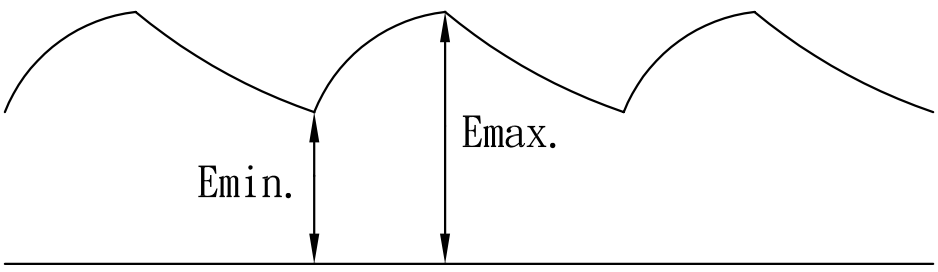
Photo MOSRELAY (I_F =5mA)



E	R
3.3V	Approx. 330 ohm
5V	Approx. 640 ohm
12V	Approx. 1.9K ohm
15V	Approx. 2.5K ohm
24V	Approx. 4.1K ohm

(1) LED forward current must be more than 5mA, at E min.

(2) LED forward current must be less than 50mA, at E max.



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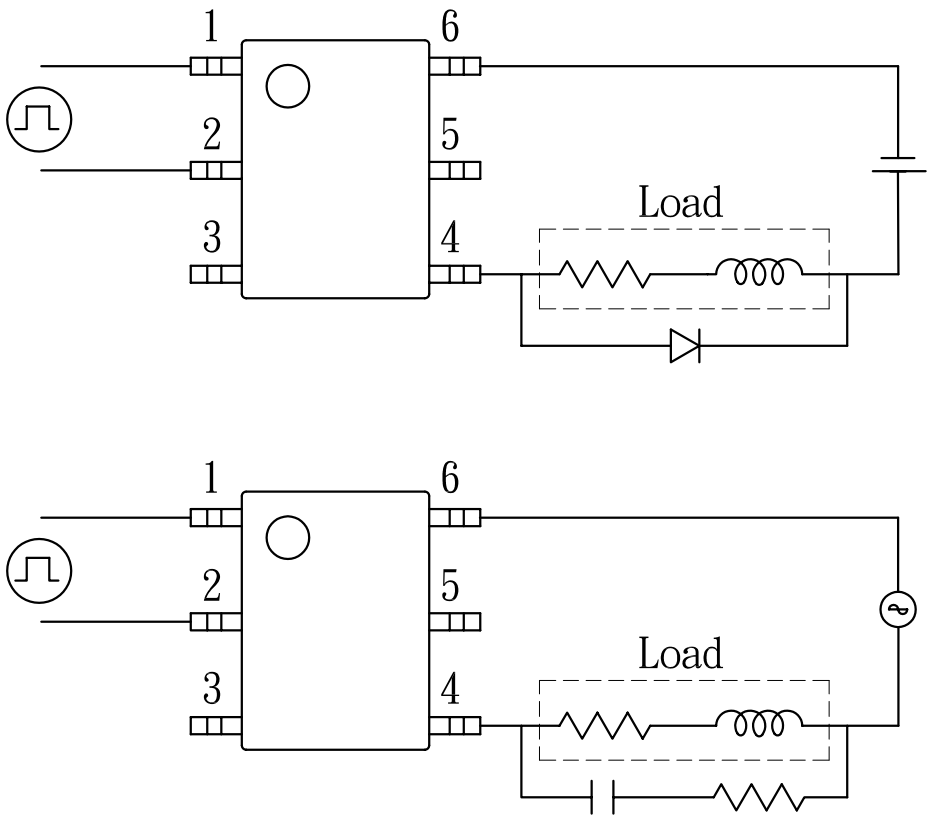
COSMO ELECTRONICS CORPORATION	PHOTO MOS RELAYS: KAQV414S	NO.62M11002	REV.
		SHEET 7 OF 7	1

USING METHODS

Regulate the spike voltage generated on the inductive load as follows



R-C Snubber